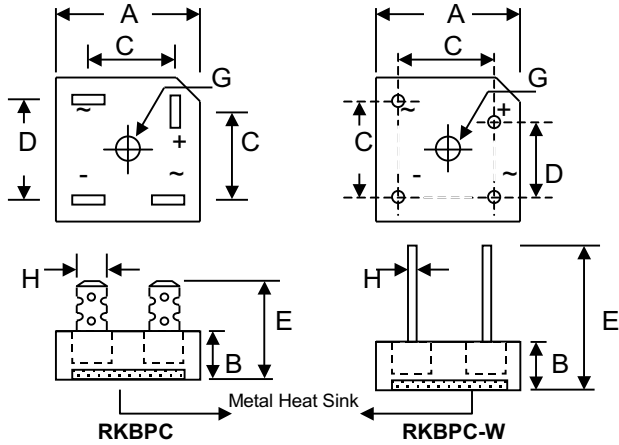


**Features**

- Diffused Junction
- Low Reverse Leakage Current
- Fast Switching, High Efficiency
- Electrically Isolated Epoxy Case for Maximum Heat Dissipation
- Case to Terminal Isolation Voltage 2500V
- UL Recognized File # E223064
- Green Products in Compliance with the RoHS Directive

**Mechanical Data**

- Case: Epoxy Case with Heat Sink Internally Mounted in the Bridge Encapsulation
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Symbols Marked on Case
- Mounting: Through Hole for #8 Screw
- Weight: RKBPC 24 grams (approx.)  
RBPC-W 21 grams (approx.)
- Marking: Type Number



Dim	RKBPC				RKBPC-W			
	Min	Max	Min	Max	Min	Max	Min	Max
A	28.40	27.40	1.118	1.079	28.40	27.40	1.118	1.079
B	10.97	11.23	0.432	0.442	10.97	11.23	0.432	0.442
C	15.70	16.70	0.618	0.657	17.10	19.10	0.673	0.752
D	17.50	18.50	0.689	0.728	10.90	11.90	0.429	0.469
E	22.86	25.40	0.90	1.00	30.50	—	1.201	—
G	Hole for #8 screw, 4.90mm(0.193inch)Ø Normina							
H	6.35 Typical		0.25 Typical		0.97Ø	1.07Ø	0.038Ø	0.042Ø
	In mm		In inch		In mm		In inch	

**Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified**

Single Phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristics	Symbol	-00/W-G	-01/W-G	-02/W-G	-04/W-G	-06/W-G	-08/W-G	-10/W-G	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Working Peak Reverse Voltage	V <sub>RWM</sub>								
DC Blocking Voltage	V <sub>R</sub>								
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectifier Output Current @T <sub>C</sub> = 55°C	I <sub>O</sub>				10 15 25 35				A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave Superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>				200 300 300 400				A
Forward Voltage Drop (per element)	V <sub>FM</sub>				1.3				V
Peak Reverse Current At Rated DC Blocking Voltage	I <sub>RM</sub>				10 500				µA
Reverse Recovery Time (Note 1)	t <sub>rr</sub>		150			250	500		nS

**Maximum Ratings and Electrical Characteristics** @ $T_A=25^\circ\text{C}$  unless otherwise specified

Typical Junction Capacitance (per element) (Note 2)	RKBPC10/W -G	C <sub>j</sub>	200	pF
	RKBPC15/W -G		200	
	RKBPC25/W -G		300	
	RKBPC35/W -G		400	
Typical Thermal Resistance Junction to Case (per element) (Note 3)	RKBPC10/W -G	R <sub>θJC</sub>	6.3	K/W
	RKBPC15/W -G		6.3	
	RKBPC25/W -G		3.8	
	RKBPC35/W -G		3.8	
RMS Isolation Voltage from Case to Lead	Viso		2500	V
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>		-65 to +125	°C

**\*Glass Passivated forms are available upon request.**

Note: 1. Measured at I<sub>F</sub> = 0.5A, I<sub>R</sub> = 1.0A, I<sub>RR</sub> = 0.25A.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

3. Thermal resistance junction to case mounted on heatsink.

Data Sheet 1428, Rev. A

**Green Products**

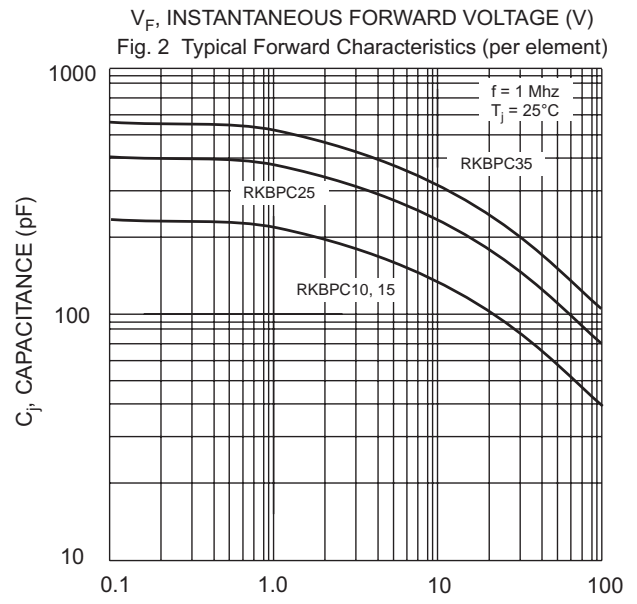
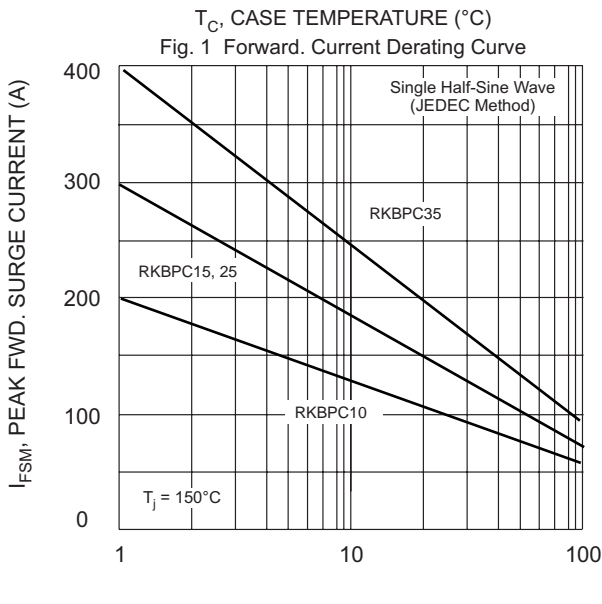
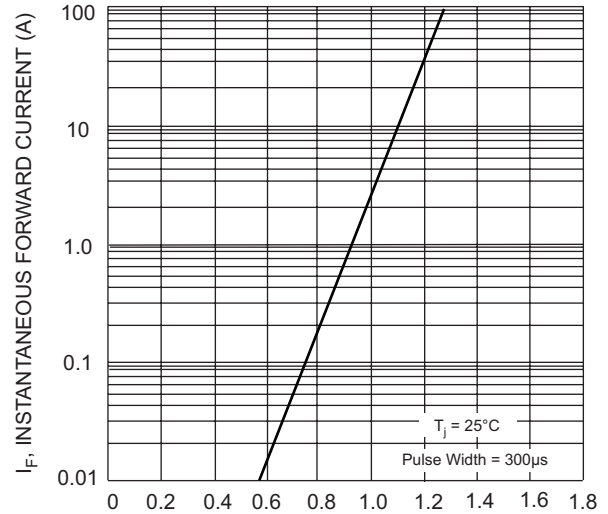
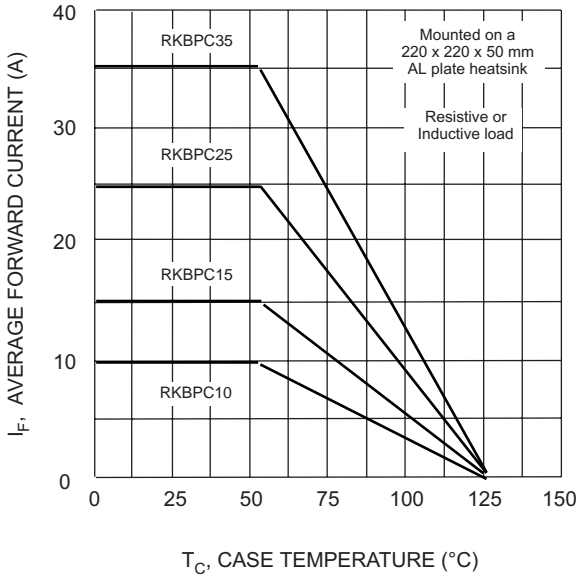


Fig. 3 Max Non-Repetitive Surge Current

Fig. 4 Typical Junction Capacitance (per element)

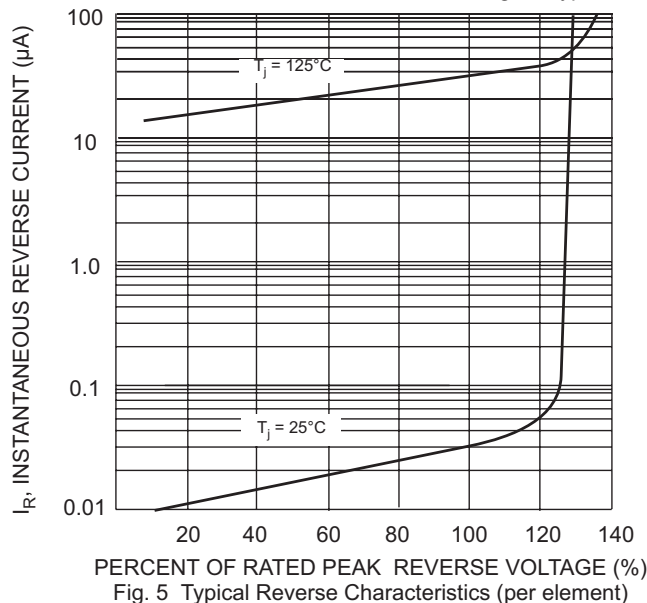


Fig. 5 Typical Reverse Characteristics (per element)

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